

LECTURE 2/1/09

ANNOUNCEMENT

QUIZZ 1 NOW DUE 2/25

INTRODUCTION TO ELECTRODYNAMICS GRIFFITHS

LAST TIME: DIELECTRICS

$\vec{P} = \epsilon_0 \chi_e \vec{E}$  : POLARIZATION: DIPOLE MOMENT PER UNIT VOLUME

$\vec{D} = \epsilon_0 \vec{E} + \epsilon_0 \chi_e \vec{E}$

$\chi_e$ : ELECTRIC SUSCEPTIBILITY

$\vec{D} = \epsilon_0 (1 + \chi_e) \vec{E}$   $\vec{D}$ : DISPLACEMENT

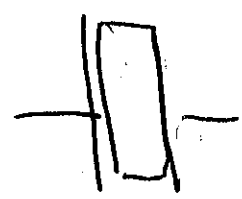
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$\epsilon = \epsilon_0 (1 + \chi_e)$

$\epsilon_0$ : PERMITTIVITY OF FREE SPACE

$\epsilon$ : PERMITTIVITY OF MATERIALS

$\kappa = \frac{\epsilon}{\epsilon_0} = \text{DIELECTRIC CONSTANT} = 1 + \chi_e$



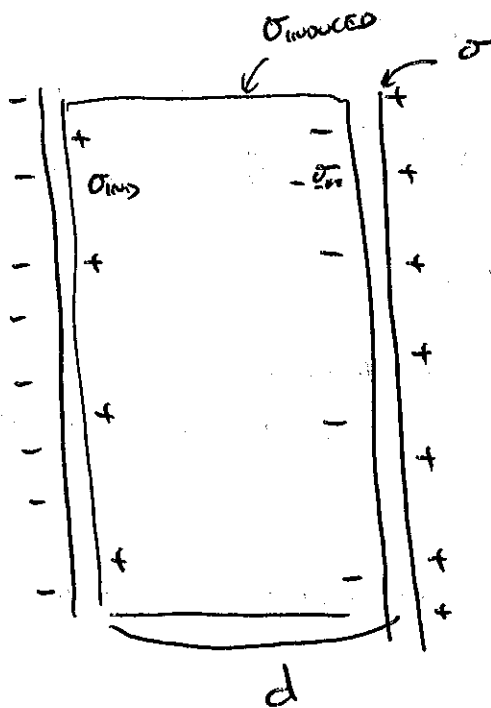
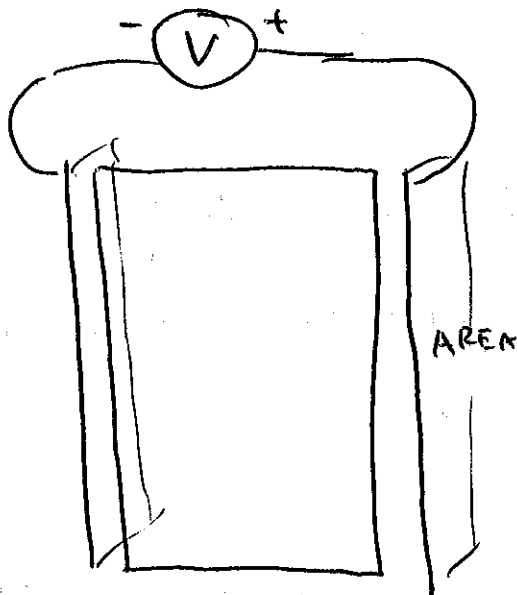
$C' = \kappa C$

REQUEST

P2

EM 352

EM 353 or Far Field



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 DIPOLE :  $q \cdot d$

$$P = \frac{\sigma_{\text{induced}} \cdot A \cdot d}{A \cdot d}$$

= DIPOLE MOMENT PER UNIT VOLUME

BUT BY DEFINITION

$$\vec{P} = \epsilon_0 \chi_0 \vec{E}$$

$$\chi_0 \vec{E} = \frac{\sigma_{INDUCED}}{\epsilon_0}$$

$$\vec{E} = \frac{\sigma_{PLATE} - \sigma_{INDUCED}}{\epsilon_0}$$

$$\chi_0 \left[ \frac{\sigma_{PLATE} - \sigma_{INDUCED}}{\epsilon_0} \right] = \frac{\sigma_{INDUCED}}{\epsilon_0}$$

$$\cancel{\chi_0} \sigma_{PLATE} = (1 + \chi_0) \sigma_{IND}$$

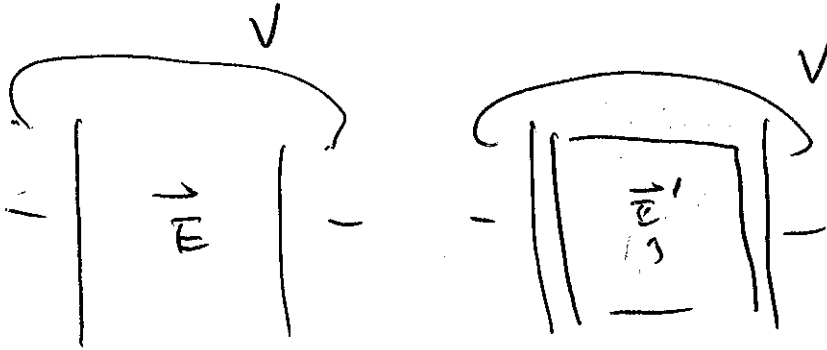
$$\chi_0 \sigma_{PLATE} = 1 + \chi_0 \sigma_{INDUCED}$$

$$\frac{\chi_0}{1 + \chi_0} \sigma_{PLATE} = \cancel{\frac{\chi_0}{\chi_0}} \sigma_{INDUCED}$$

$$\vec{E} = \frac{\sigma_{PLATE} - \sigma_{INDUCED}}{\epsilon_0} = \cancel{\frac{1 + \chi_0}{\chi_0}} \frac{\sigma}{\epsilon_0} \left[ 1 - \frac{\chi_0}{1 + \chi_0} \right]$$

$$\vec{E} = \frac{\sigma_{PLATE}}{\epsilon_0} \frac{1}{[1 + \chi_0]}$$

BUT  $k = \frac{\epsilon}{\epsilon_0} = \text{DIELECTRIC CONST} = 1 + \chi >$



$$\underline{\underline{E'}} = \frac{E}{k}$$

BOOK 26.7

$$\vec{E} = \frac{\sigma_{\text{PLATE}}}{\epsilon_0} \left[ \frac{1}{1 + k\epsilon_0} \right] = \frac{\sigma_p}{\epsilon_0} \frac{1}{k}$$

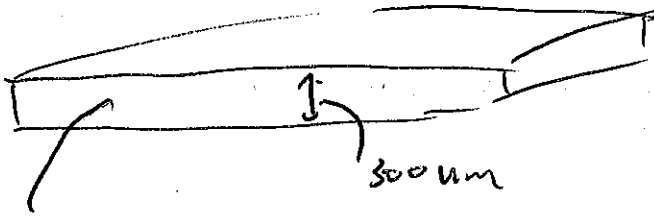
$$\Delta V = \frac{\sigma_p d}{\epsilon_0 k} = \frac{Q_p d}{k \epsilon_0 A}$$

$$\frac{k \epsilon_0 A}{d} \Delta V = Q_p$$

$$C' = \frac{k \epsilon_0 A}{d} \quad \underline{\underline{\text{INCREASES}}}$$

EXAMPLE

CALCULATE CAPACITANCE OF SiO<sub>2</sub>



$$\frac{\epsilon}{\epsilon_0} = 3.9 \quad \text{SiO}_2$$

$$C = 3.9 \cdot \frac{\epsilon_0 A}{d} \quad \text{FARADS}$$

$$= \frac{3.9 \cdot 8.85 \times 10^{-12} \text{ (m}^2\text{)}}{300 \times 10^{-9}}$$

$$\boxed{C/m^2} = 1.15 \times 10^{-4} \text{ F/m}^2$$

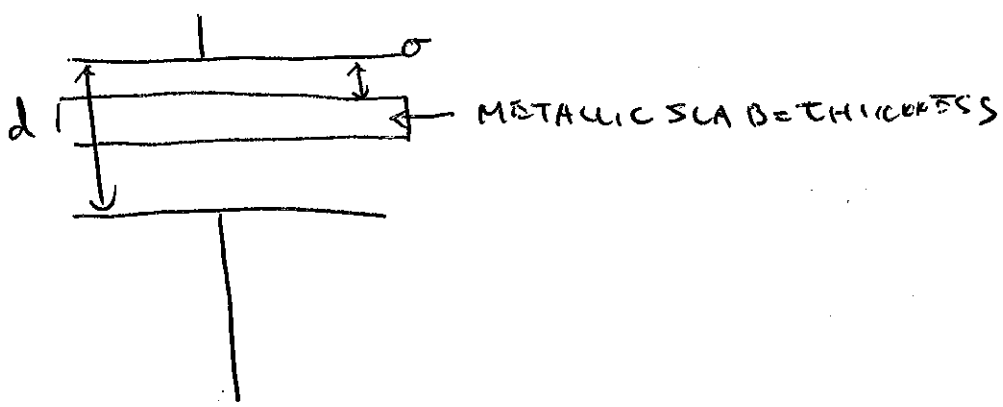
$$C \Delta V = Q$$

SO PER 1 VOLT

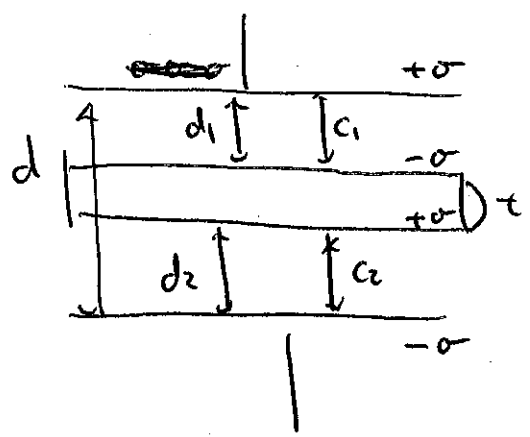
$$1.15 \times 10^{-4} \text{ F/m}^2 \cdot 1 \text{ V} = 1.15 \times 10^{-4} \text{ C/m}^2$$

$$\frac{1.15 \times 10^{-4}}{1.603 \times 10^{-19}} = 7.2 \times 10^{14} \text{ e/m}^2 \cdot \text{V}$$

EXAMPLE 2



CAPACITANCE BEFORE =  $\frac{\epsilon_0 A}{d}$



AFTER =  $\frac{1}{C_{TOTAL}} = \frac{1}{C_1} + \frac{1}{C_2}$

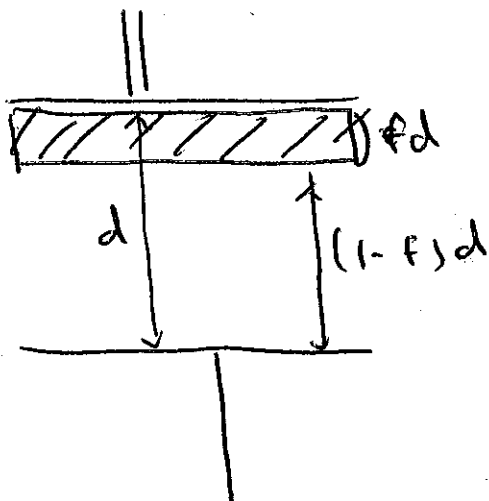
$d_1 = \frac{d-t}{2} = d_2$

$C_1 = C_2 = \frac{\epsilon_0 A}{\frac{d-t}{2}} = \frac{2\epsilon_0 A}{d-t}$

$\frac{1}{C_{TOTAL}} = \frac{1}{C_1} + \frac{1}{C_2} = \frac{2}{C_2} = \frac{2}{\frac{2\epsilon_0 A}{d-t}}$

$\frac{1}{C_T} = \frac{d-t}{\epsilon_0 A}$

$$C_T = \frac{\epsilon_0 A}{d-t}$$



⇒ EQUIVALENT TO

$$\frac{1}{C_T} = \frac{1}{C_d} + \frac{1}{C_v}$$

$$C_d = \frac{k \epsilon_0 A}{fd} \quad C_v = \frac{\epsilon_0 A}{(1-f)d}$$

$$\frac{1}{C_T} = \frac{fd}{k \epsilon_0 A} + \frac{(1-f)d}{\epsilon_0 A}$$

$$= \frac{fd + k(1-f)d}{k \epsilon_0 A} \Rightarrow C_T = \frac{k \epsilon_0 A}{fd + (k-1)f d}$$

(if  $f=0$   $f=1$ )

$$C_T = \frac{\epsilon_0 A}{d} \quad C_T = \frac{k \epsilon_0 A}{d}$$

$$\nabla \cdot \vec{E} = \frac{\rho}{\epsilon_0} \quad \text{GAUSS'S LAW}$$

$$\nabla \cdot \vec{D} = \rho_f$$

$$\rho = \rho_f + \rho_{bound}$$

$$\rho_b = -\nabla \cdot \vec{P}$$